

NTE56065 TRIAC, 600V_{RM}, 12A, High Commutation

Description:

The NTE56065 is a glass passivated, high commutation TRIAC in an isolated full—pack type package designed for use in circuits where high static and dynamic dV/dt and high dl/dt can occur. This device will commutate the full rated RMS current at the maximum rated junction temperature, without the aid of a snubber.

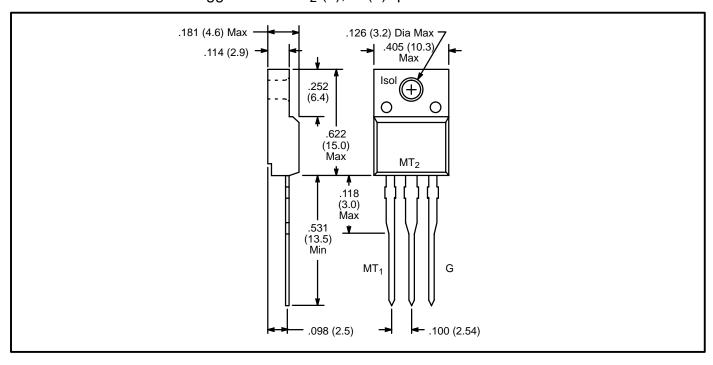
Absolute Maximum Ratings:
Repetitive Peak Off–Sate Voltage (Note 1), V _{DRM} 600V
RMS On–State Current (Full Sine Wave, $T_{HS} \le 56^{\circ}C$), $I_{T}(RMS)$
Non-Repetitive Peak On-State Current, I _{TSM}
(Full Sine Wave, $T_J = +25^{\circ}C$ prior to Surge)
t = 20ms
I^2 t for Fusing (t = 10ms), I^2 t
Repetitive Rate-of-Rise of On-State Current after Triggering, dl _T /dt
$(I_{TM} = 20A, I_G = 0.2A, dI_G/dt = 0.2A/\mu s)$
Peak Gate Current, I _{GM} 2A
Peak Gate Voltage, V _{GM} 5V
Peak Gate Power, P _{GM} 5W
Average Gate Power (Over Any 20ms Period), P _{G(AV)}
Operating Junction Temperature, T _J +125°C
Storage Temperature Range, T _{stg} –40° to +150°C
Thermal Resistance, Junction-to-Heatsink (Full or Half Cycle), RthJHS
With Heatsink Compound 4.0K/W
Without Heatsink Compound 5.5K/W
Typical Thermal Resistance, Junction-to-Ambient, R _{thJA}

Note 1. Although not recommended, off–state voltages up to 800V may be applied without damage, but the TRIAC may switch to the on–state. The rate–of–rise of current should not exceed 15A/μs.

Electrical Characteristics: $(T_J = +25^{\circ}C \text{ unless otherwise specfied})$

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static Characteristics	•					
Gate Trigger Current MT ₂ (+), G (+)	I _{GT}	V _D = 12V, I _T = 0.1A, Note 2	2	18	50	mA
MT ₂ (+), G (–)			2	21	50	mΑ
MT ₂ (–), G (–)			2	34	50	mA
Latching Current MT ₂ (+), G (+)	ΙL	V _D = 12V, I _T = 0.1A	_	31	60	mA
MT ₂ (+), G (–)			_	34	90	mA
MT ₂ (–), G (–)			_	30	60	mA
Holding Current	I _H	$V_D = 12V, I_T = 0.1A$	_	31	60	mA
On–State Voltage	V_{T}	I _T = 17A	_	1.3	1.6	V
Gate Trigger Voltage	V_{GT}	$V_D = 12V, I_T = 0.1A$	-	0.7	1.5	V
		$V_D = 400V$, $I_T = 0.1A$, $T_J = +125$ °C	0.25	0.4	_	V
Off-State Leakage Current	I _D	$V_D = 600V, T_J = +125^{\circ}C$	_	0.1	0.5	mA
Dynamic Characteristics	•					
Critical Rate-of-Rise of Off-State Voltage	dV _D /dt	V _{DM} = 402V, T _J = +125°C, Exponential Waveform, Gate Open	1000	4000	_	V/μs
Critical Rate-of-Change of Commutating Current	dl _{com} /dt	V_{DM} = 400V, T_J = +125°C, I_T RMS = 12A, without Snubber, Gate Open	_	24	_	A/ms
Gate Controlled Turn-On Time	t _{gt}	I_{TM} = 12A, V_D = V_{DRM} max, I_G = 0.1A, dI_G /dt = 5A/ μ s	_	2	_	μs
Isolation Characteristics	•		•	•	•	•
RMS Isolation Voltage from All 3 Pins to External Heatsink	V _{ISOL}	f = 50 − 60Hz, Sinusoidal Waveform, R.H. ≤ 65%, Clean and Dustfree	_	_	2500	V
Capacitance from T2 to External Heatsink	C _{ISOL}	f = 1MHz	_	10	_	pF

Note 2. Device does not trigger in the MT_2 (–), G (+) quadrant.



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Triacs category:

Click to view products by NTE manufacturer:

Other Similar products are found below:

ACST435-8B LIC01-215B-TR T2035H-6G BT137-600-0Q Z0410NF 1AA2 098128C 620675E T1610-600G-TR Z0409MF0AA2 Z0109NA 2AL2 ACS108-8SA-AP ACS108-8SN-TR ACST1635T-8FP BCR16PM-12LG#B00 BCR20RM-30LA#B00 T1205-600G-TR CMA60MT1600NHR NTE5611 NTE5612 NTE5613 NTE5621 NTE5623 NTE5629 NTE5638-08 NTE5688 NTE5689 NTE5690 T1235T-8I BTA312-600CT.127 T1210T-8G-TR T1210T-8G BT136S-600E,118 BT137B-800G,118 Z0109NN0,135 MAC4DLM-1G BT137-600E,127 BT137X-600D BT148W-600R,115 BT258-500R,127 BTA08-800BW3G BTA140-800,127 BTA30-600CW3G BTB08-800BW3G BTB16-600CW3G BTB16-600CW3G Z0405M-0AA2 Z0410MF0AA2 Z0109MN,135 T825T-6I